

GC-1330-60-TO-200-A

Straight stripe gain chip on TO-header



Features:

- Optimized for wavelength locked operation in external cavity
- Broad hopping free tuning range
- High SMSR
- No self-lasing up to maximum operating current
- TE polarization

Applications:

- External cavity diode lasers
- Tunable laser sources

Recommended Operating Conditions

Parameter	Min.	Typ.	Max.	Unit
Heatsink Temperature	20	25	30	°C
Forward Current*			800	mA
Optical Feedback**		20		%

*No self-lasing up to maximum current

** doesn't include coupling efficiency to chip.

Tunability Characteristics

Batch qualified @ CW, 25C, 800mA, external cavity in Littman configuration with 20% feedback

Parameter	Min.	Typ.	Max.	Unit
Wavelength of Maximum Power	1320	1340	1340	nm
Output Power @ 1340nm	150	210		mW
Central Wavelength of Tuning Range	1320	1330	1340	nm
Tuning Range Width (full)		60		nm
Side-Mode Suppression Ratio (SMSR) @ 1340nm		55		dB

Amplified Spontaneous Emission (ASE) Characteristics

Tested for each sample @ CW, 25C, 800mA, without feedback

Parameter	Min.	Typ.	Max.	Unit
Output Power		70		mW
Forward Voltage		1.6	2	V
Mean Wavelength		1340		nm
Bandwidth (FWHM)*		2		nm
Fast Axis Beam Divergence (FWHM)	35	38	45	deg
Slow Axis Beam Divergence (FWHM)	4	5	11	deg
Polarization		TE		

* Radiation coupled in single-mode fiber without lens and measured by OSA with 1 nm resolution.

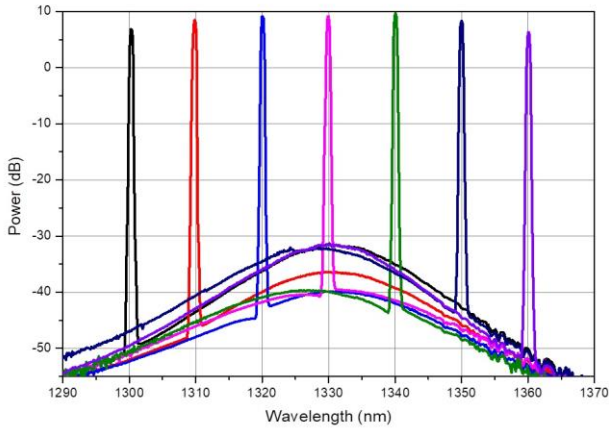
Chip Parameters

Parameter	Min.	Typ.	Max.	Unit
Chip length		3		mm
Back-reflection from Front Facet			0.1	%
Back-reflection from Back Facet	90	99		%

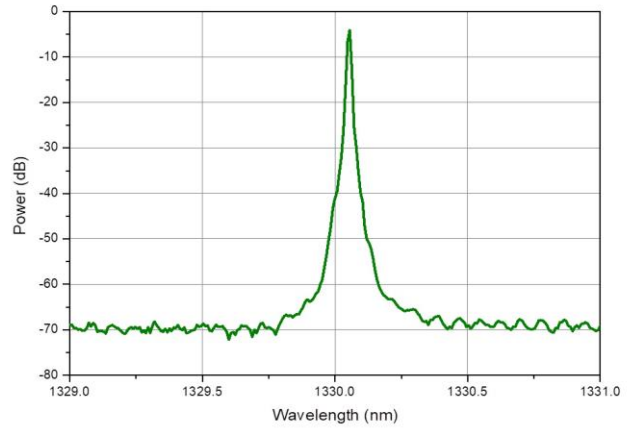
Typical Performance in External Cavity (for reference only)

@ CW, recommended operating conditions, Littman configuration

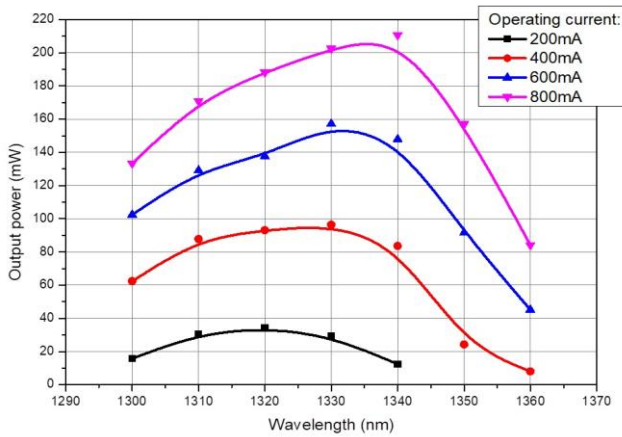
Optical spectra (res. 0.5 nm)



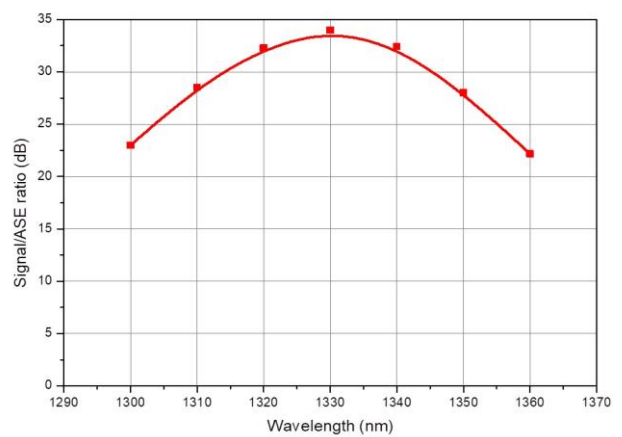
Optical spectrum (res. 10 pm)



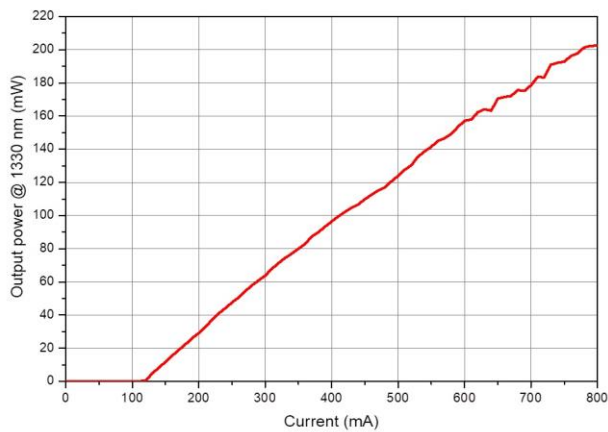
Output power spectra



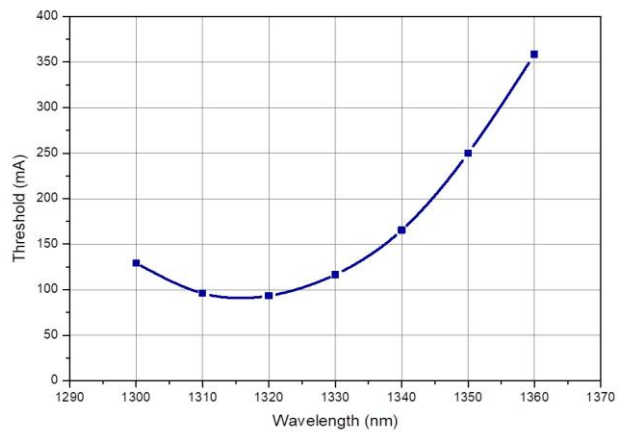
Integrated Signal/ASE ratio



Output power @ 1340nm

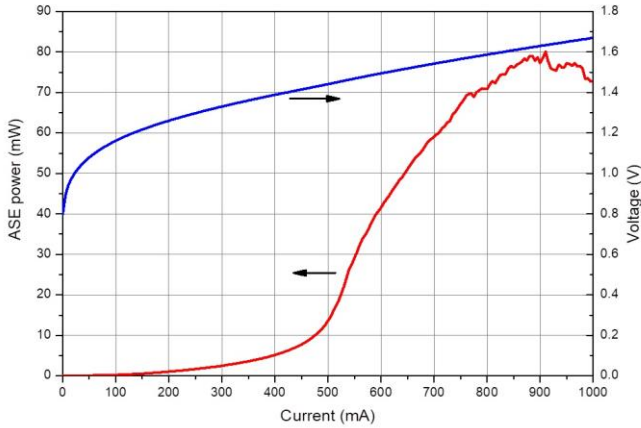


Threshold current

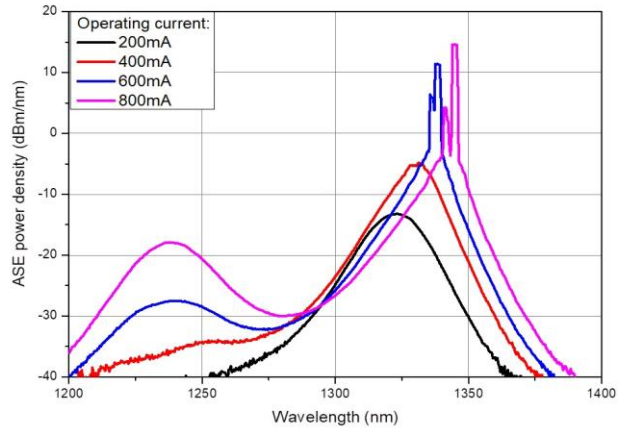


Typical Performance without feedback (for reference only)

L-I-V curve



ASE spectra (res. 1nm)



Absolute Maximum Ratings

Parameter	Min	Max	Unit
Forward Current @ 20% feedback		1000	mA
Optical Feedback (doesn't include coupling to a chip)		30	%
Reverse Voltage		1	V
Operating temperature (above dew point)	-10	60	°C
Storage Temperature (in original hermetically sealed package)	-40	85	°C

